

2SB1357

Transistor, PNP

Features

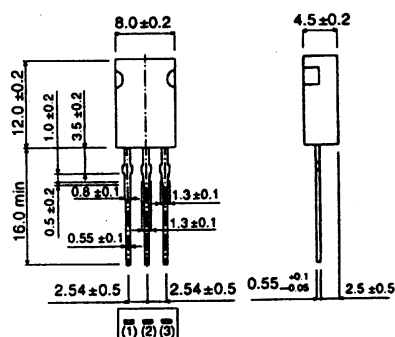
- available in HRT package
- low collector saturation voltage, typically $V_{CE(sat)} = -0.5 \text{ V}$ at $I_C/I_B = -2 \text{ A}/-0.2 \text{ A}$
- wide safe operating area (SOA)

Applications

- power amplifier

Dimensions (Units : mm)

2SB1357 (HRT)



- (1) Base
(2) Collector
(3) Emitter

Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit	Conditions
Collector-to-base voltage	V_{CBO}	-60	V	
Collector-to-emitter voltage	V_{CEO}	-50	V	
Emitter-to-base voltage	V_{EBO}	-5	V	
Collector current	I_C	-3	A	Continuous (dc)
		-4.5	A	Single pulse, $P_W = 100 \text{ ms}$
Collector dissipation	P_C	1.8	W	
Junction temperature	T_j	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 ~ +150	$^\circ\text{C}$	

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Electrical characteristics (unless otherwise noted, $T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min	Typical	Max	Unit	Conditions
Collector-to-base breakdown voltage	BV_{CBO}	-60			V	$I_C = -50\ \mu\text{A}$
Collector-to-emitter breakdown voltage	BV_{CEO}	-50			V	$I_C = -1\ \text{mA}$
Emitter-to-base breakdown voltage	BV_{EBO}	-5				$I_E = -50\ \mu\text{A}$
Collector cutoff current	I_{CBO}			-1.0	μA	$V_{CB} = -40\ \text{V}$
Emitter cutoff current	I_{EBO}			-1.0	μA	$V_{EB} = -4\ \text{V}$
DC current gain	h_{FE}	60		320		$V_{CE} = -3\ \text{V}$, $I_C = -0.5\ \text{A}$, single pulse
Collector-to-emitter saturation voltage	$V_{CE(sat)}$		-0.5	-1.0	V	$I_C/I_B = -2\ \text{A}/-0.2\ \text{A}$, single pulse
Base-to-emitter saturation voltage	$V_{BE(sat)}$			-1.5	V	$I_C/I_B = -2\ \text{A}/-0.2\ \text{A}$, single pulse
Transition frequency	f_T		70		MHz	$V_{CE} = -5\ \text{V}$, $I_E = 0.5\ \text{A}$, $f = 30\ \text{MHz}$
Output capacitance	C_{ob}		50		pF	$V_{CB} = -10\ \text{V}$, $I_E = 0\ \text{A}$, $f = 1\ \text{MHz}$

h_{FE} rankings

Item	D	E	F
h_{FE}	60 ~ 120	100 ~ 200	160 ~ 320

Electrical characteristic curves

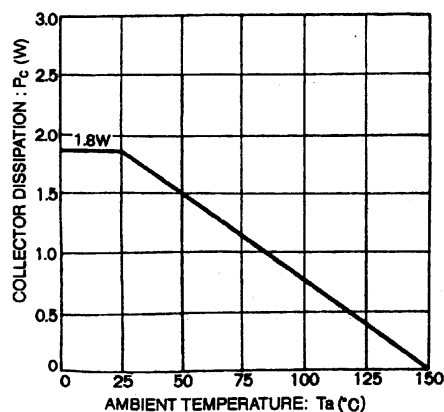


Figure 1

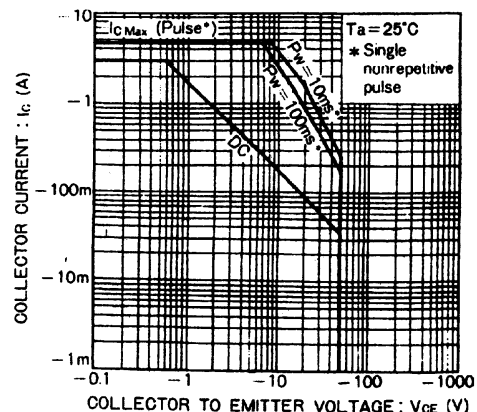


Figure 2

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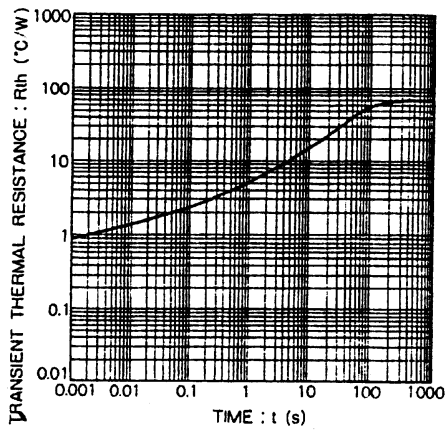


Figure 3

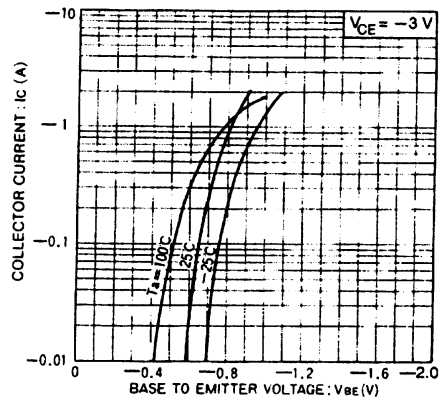


Figure 4

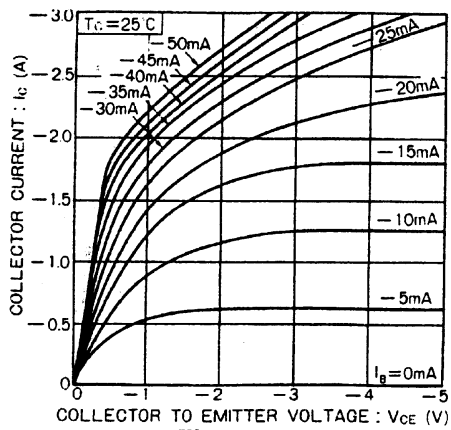


Figure 5

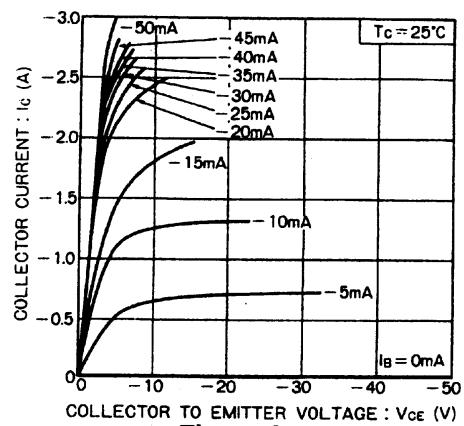


Figure 6

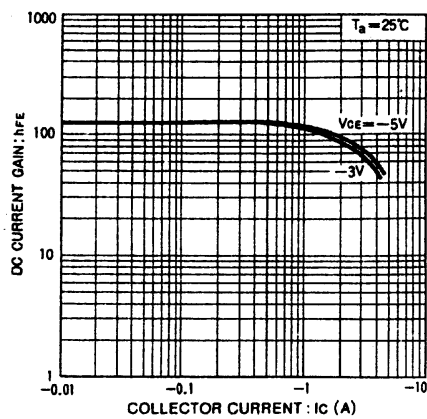


Figure 7

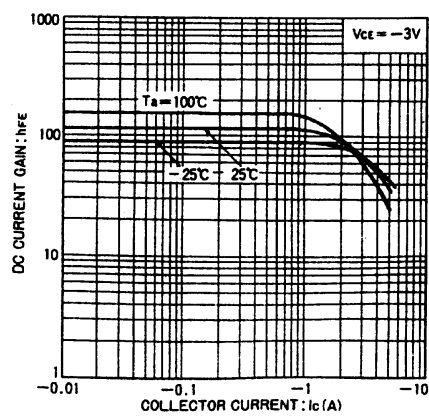


Figure 8

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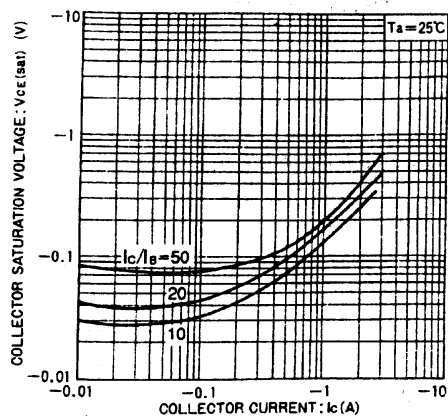


Figure 9

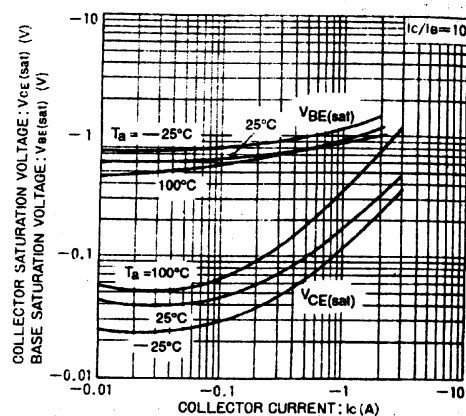


Figure 10

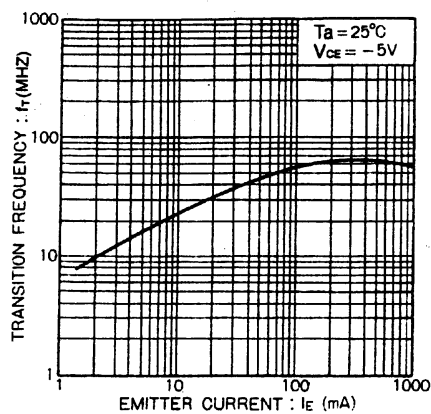


Figure 11

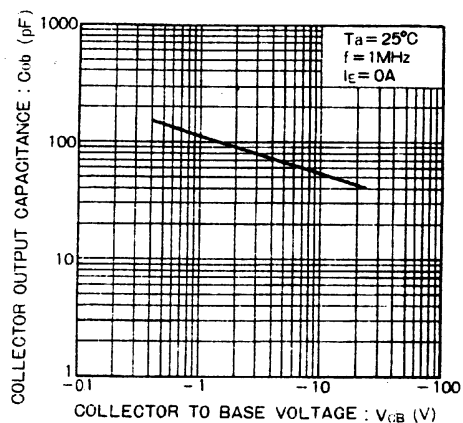


Figure 12

Ordering information

Package	Tape
Code	T114
Basic order quantity	1 000
2SB1357	★
★ = Standard, ☆ = Semi-standard, * = Special order	

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